

# Silicon Carbide (SiC) Schottky Diode – EliteSiC, 8 A, 650 V, D1, TO-220F-2L

## FFSPF0865A

### Description

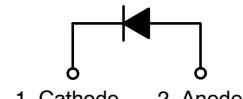
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

### Features

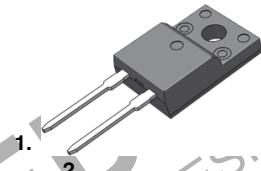
- Max Junction Temperature 175°C
- Avalanche Rated 49 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb-Free, Halogen Free/BFR Free and RoHS Compliant

### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

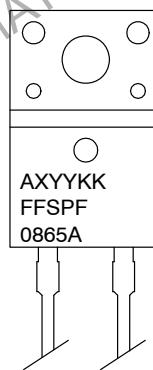


Schottky Diode



TO-220 FP / TO-220F-2FS  
CASE 221AS

### MARKING DIAGRAM



A = Assembly Plant Code  
XYY = Data Code (Year & Week)  
KK = Lot Traceability Code  
FFSPF0865A = Specific Device Code

### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

# FFSPF0865A

## ABSOLUTE MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ , Unless otherwise noted)

Symbol	Parameter	FFSPF0865A	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	650	V
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	49	mJ
$I_F$	Continuous Rectified Forward Current @ $T_C < 124^\circ\text{C}$	8	A
	Continuous Rectified Forward Current @ $T_C < 135^\circ\text{C}$	6.8	
$I_{F, \text{Max}}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}, 10\ \mu\text{s}$	A
		$T_C = 150^\circ\text{C}, 10\ \mu\text{s}$	A
$I_{F, \text{SM}}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\ \text{ms}$	A
$I_{F, \text{RM}}$	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\ \text{ms}$	A
$P_{\text{tot}}$	Power Dissipation	$T_C = 25^\circ\text{C}$	W
		$T_C = 150^\circ\text{C}$	W
$T_J, T_{\text{STG}}$	Operating and Storage Junction Temperature Range	-55 to + 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta\text{JC}}$	Thermal Resistance, Junction to Case, Max.	4.0	°C/W

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
$V_F$	Forward Voltage	$I_F = 8\ \text{A}, T_C = 25^\circ\text{C}$	-	1.50	1.75	V
		$I_F = 8\ \text{A}, T_C = 125^\circ\text{C}$	-	1.6	2.0	
		$I_F = 8\ \text{A}, T_C = 175^\circ\text{C}$	-	1.72	2.4	
$I_R$	Reverse Current	$V_R = 650\ \text{V}, T_C = 25^\circ\text{C}$	-	-	200	μA
		$V_R = 650\ \text{V}, T_C = 125^\circ\text{C}$	-	-	400	
		$V_R = 650\ \text{V}, T_C = 175^\circ\text{C}$	-	-	600	
$Q_C$	Total Capacitive Charge	$V = 400\ \text{V}$	-	27	-	nC
$C$	Total Capacitance	$V_R = 1\ \text{V}, f = 100\ \text{kHz}$	-	463	-	pF
		$V_R = 200\ \text{V}, f = 100\ \text{kHz}$	-	48	-	
		$V_R = 400\ \text{V}, f = 100\ \text{kHz}$	-	38	-	

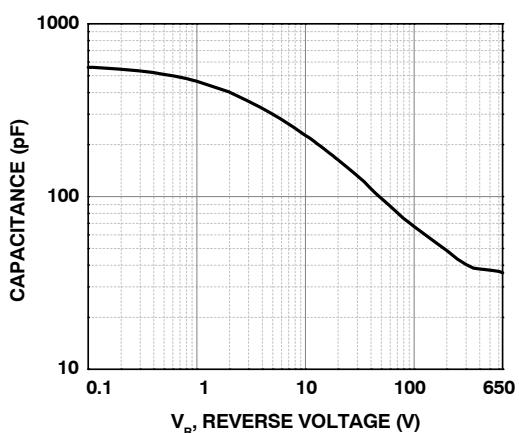
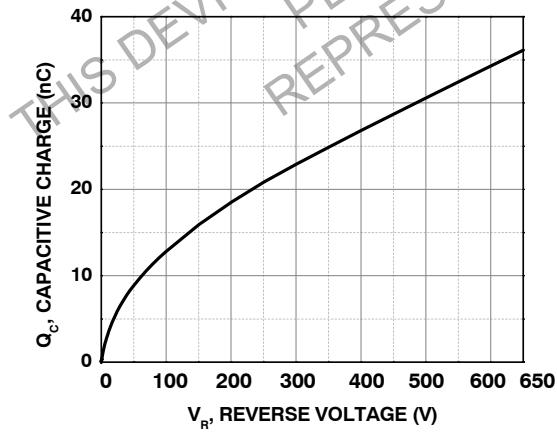
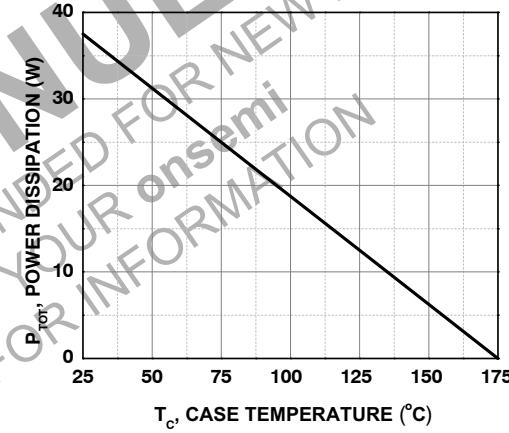
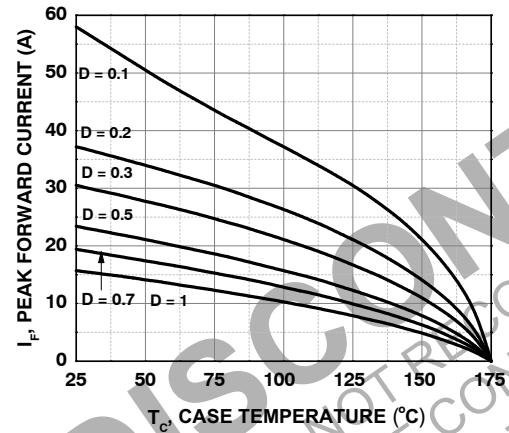
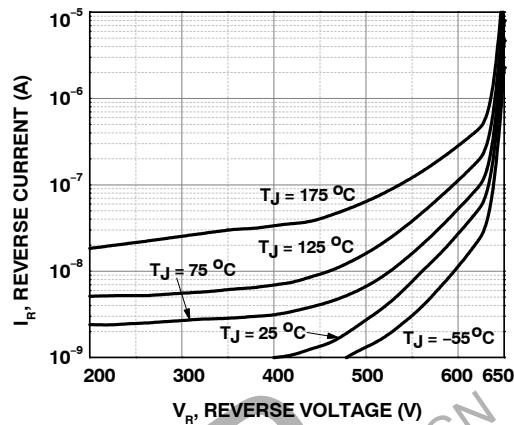
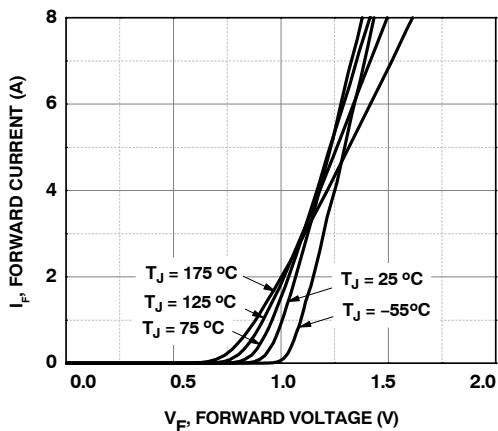
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1.  $E_{AS}$  of 49 mJ is based on starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.5\ \text{mH}$ ,  $I_{AS} = 14\ \text{A}$ ,  $V = 50\ \text{V}$ .

## ORDERING INFORMATION

Device	Marking	Package	Packing Method	Quantity
FFSPF0865A	FFSPF0865A	TO-220 FP / TO-220F-2FS	Tube	50 units

**TYPICAL CHARACTERISTICS**  
( $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)



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( $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)

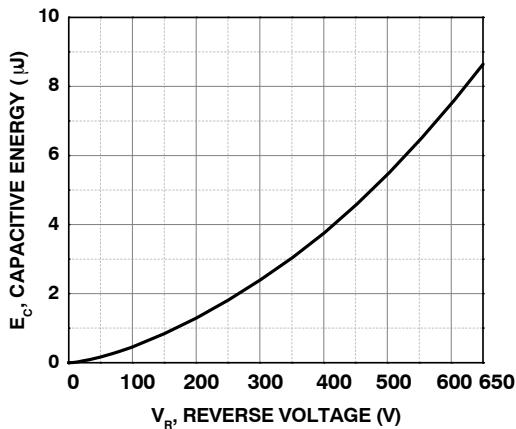


Figure 7. Capacitance Stored Energy

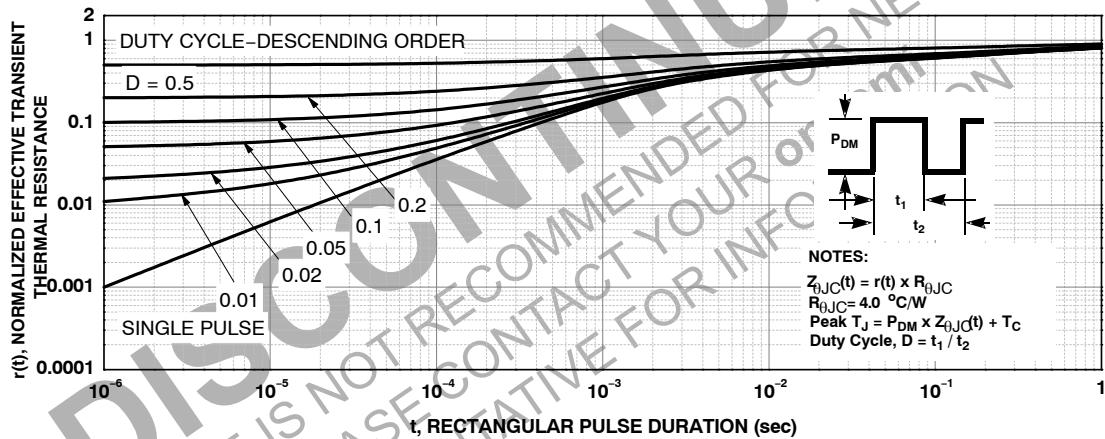


Figure 8. Junction-to-Case Transient Thermal Response Curve

**TEST CIRCUIT AND WAVEFORMS**

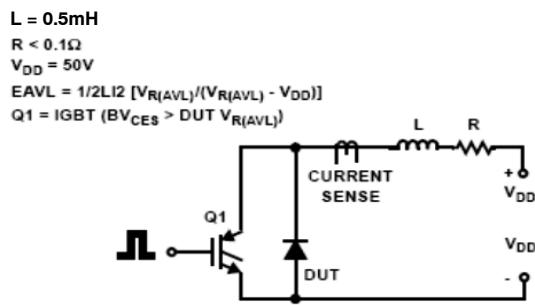
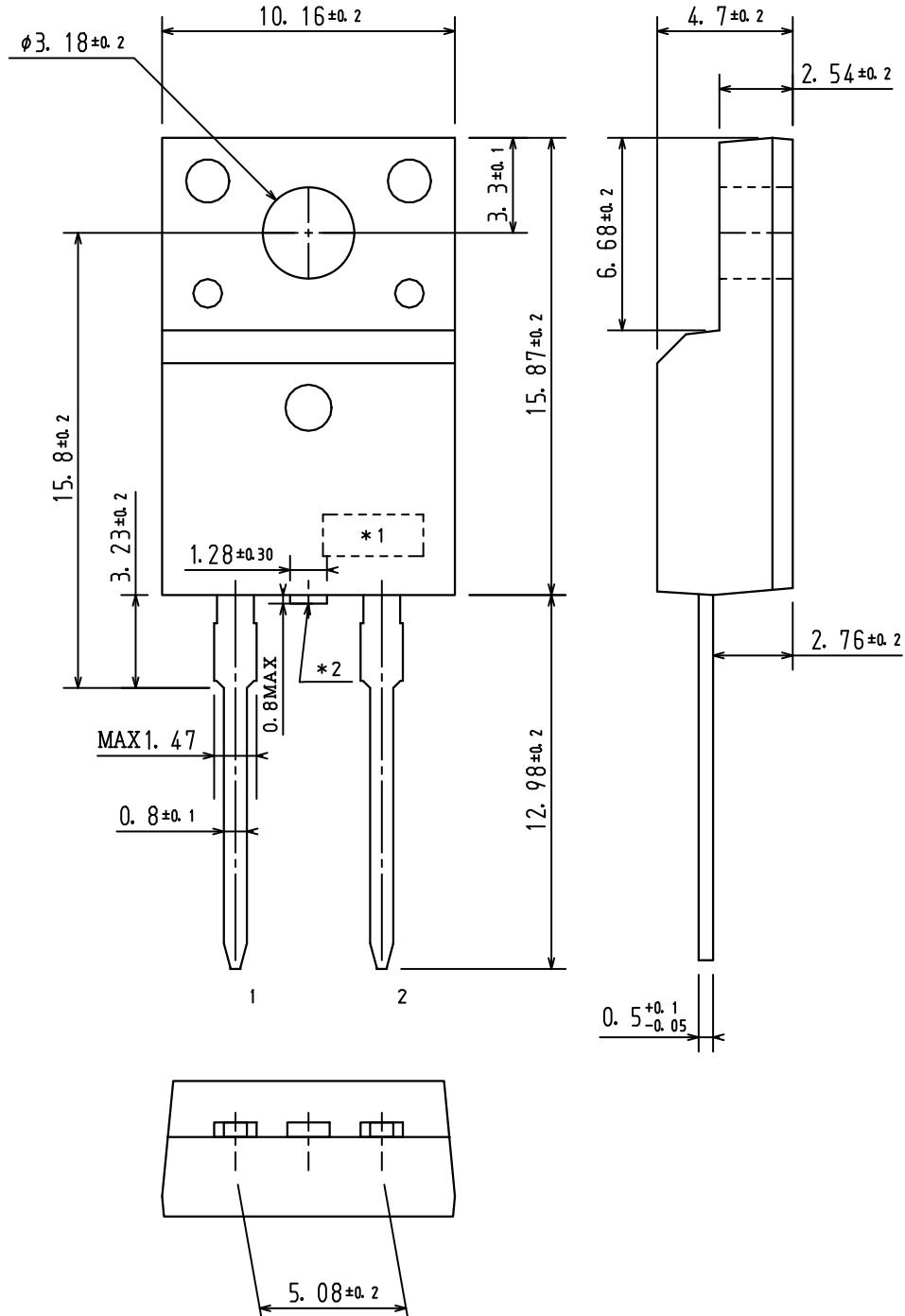


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

TO-220 Fullpack, 2-Lead / TO-220F-2FS  
CASE 221AS  
ISSUE O

DATE 29 FEB 2012



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DESCRIPTION:	TO-220 FULLPACK, 2-LEAD / TO-220F-2FS	PAGE 1 OF 1

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